## NSN 5961-01-533-0427

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-533-0427 **Inclosure Material:** Plastic **Overall Length:** Between 0.330 inches and 0.350 inches **Overall Diameter:** Between 0.130 inches and 0.145 inches **Function For Which Designed:** Rectifier **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 working peak reverse voltage **Current Rating Per Characteristic:** 3.00 amperes collector current, dc **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Product Name:** Medium power silicon rectifier diode **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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